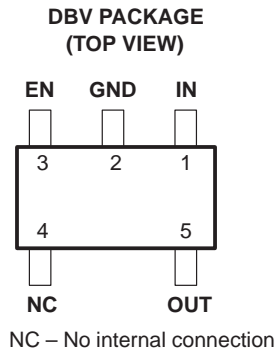


# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050 LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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- 50-mA Low-Dropout Regulator
- Fixed Output Voltage Options: 5 V, 3.8 V, 3.3 V, 3.2 V, and 3 V
- Dropout Typically 120 mV at 50 mA
- Thermal Protection
- Less Than 1  $\mu$ A Quiescent Current in Shutdown
- $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  Operating Junction Temperature Range
- 5-Pin SOT-23 Package
- ESD Protection Verified to 1.5 kV Human Body Model (HBM) per MIL-STD-883C



## description

The TPS760xx is a 50mA, low dropout (LDO) voltage regulator designed specifically for battery-powered applications. A proprietary BiCMOS fabrication process allows the TPS760xx to provide outstanding performance in all specifications critical to battery-powered operation.

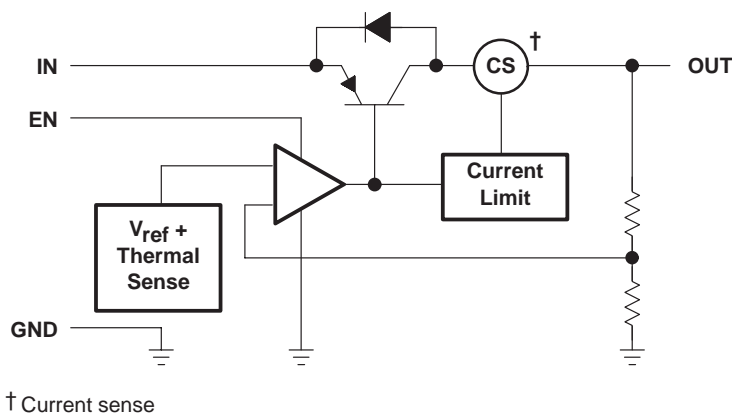
The TPS760xx is available in a space-saving SOT-23 package and operates over a junction temperature range of  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ .

AVAILABLE OPTIONS

$T_J$	VOLTAGE	PACKAGE	PART NUMBER	SYMBOL
$-40^{\circ}\text{C}$ to $125^{\circ}\text{C}$	3 V	SOT-23	TPS76030DBVR	PAGI
	3.2 V		TPS76032DBVR	PAOI
	3.3 V		TPS76033DBVR	PAHI
	3.8 V		TPS76038DBVR	PAJI
	5 V		TPS76050DBVR	PANI

NOTE: The DBV package is available taped and reeled only.

## functional block diagram



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS  
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# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050

## LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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### Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
IN	1	I	Input voltage
GND	2		Ground
EN	3	I	Enable input
NC	4		No connection
OUT	5	O	Regulated output voltage

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Input voltage range, $V_I$ <sup>‡</sup>	–0.3 V to 16 V
Voltage range at EN	–0.3 V to $V_I + 0.3$ V
Peak output current	internally limited
Continuous total dissipation	See dissipation table
Operating junction temperature range, $T_J$	–40°C to 150°C
Storage temperature range, $T_{stg}$	–65°C to 150°C
ESD rating, HBM	1.5 kV

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>‡</sup> All voltages are with respect to device GND pin.

DISSIPATION RATING TABLE

	PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
Recommended	DBV	350 mW	3.5 mW/°C	192 mW	140 mW
Maximum	DBV	437 mW	3.5 mW/°C	280 mW	227 mW

### recommended operating conditions

		MIN	NOM	MAX	UNIT
Input voltage, $V_I$	TPS76030	3.2		16	V
	TPS76032	3.4		16	V
	TPS76033	3.5		16	V
	TPS76038	4		16	V
	TPS76050	5.2		16	V
Continuous output current, $I_O$		0		50	mA
Operating junction temperature, $T_J$		–40		125	°C



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# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050

## LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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**electrical characteristics over recommended operating free-air temperature range,  
 $V_I = V_{O(nom)} + 1\text{ V}$ ,  $I_O = 1\text{ mA}$ ,  $EN = V_I$ ,  $C_O = 2.2\text{ }\mu\text{F}$  (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V <sub>O</sub>	Output voltage	TPS76030	T <sub>J</sub> = 25°C	2.96	3	3.04	V
			T <sub>J</sub> = 25°C, 1 mA < I <sub>O</sub> < 50 mA	2.92		3.04	V
			1 mA < I <sub>O</sub> < 50 mA	2.91		3.07	V
	TPS76032	T <sub>J</sub> = 25°C	3.16	3.2	3.24	V	
			T <sub>J</sub> = 25°C, 1 mA < I <sub>O</sub> < 50 mA	3.13		3.24	V
			1 mA < I <sub>O</sub> < 50 mA	3.1		3.3	V
	TPS76033	T <sub>J</sub> = 25°C	3.26	3.3	3.34	V	
			T <sub>J</sub> = 25°C, 1 mA < I <sub>O</sub> < 50 mA	3.23		3.34	V
			1 mA < I <sub>O</sub> < 50 mA	3.2		3.4	V
	TPS76038	T <sub>J</sub> = 25°C	3.76	3.8	3.84	V	
			T <sub>J</sub> = 25°C, 1 mA < I <sub>O</sub> < 50 mA	3.73		3.84	V
			1 mA < I <sub>O</sub> < 50 mA	3.7		3.9	V
	TPS76050	T <sub>J</sub> = 25°C	4.95	5	5.05	V	
			T <sub>J</sub> = 25°C, 1 mA < I <sub>O</sub> < 50 mA	4.91		5.05	V
			1 mA < I <sub>O</sub> < 50 mA	4.89		5.1	V
I <sub>I(standby)</sub>	Standby current	EN = 0 V			1	μA	
Quiescent current (GND current)		I <sub>O</sub> = 0 mA, T <sub>J</sub> = 25°C		90	115	μA	
		I <sub>O</sub> = 0 mA			130		
		I <sub>O</sub> = 1 mA, T <sub>J</sub> = 25°C		100	130		
		I <sub>O</sub> = 1 mA			170		
		I <sub>O</sub> = 10 mA, T <sub>J</sub> = 25°C		190	215		
		I <sub>O</sub> = 10 mA			460		
		I <sub>O</sub> = 50 mA, T <sub>J</sub> = 25°C		850	1100		
		I <sub>O</sub> = 50 mA			1200		
Input regulation	TPS76030	4 V < V <sub>I</sub> < 16, I <sub>O</sub> = 1 mA		3	10	mV	
	TPS76032	4.2 V < V <sub>I</sub> < 16, I <sub>O</sub> = 1 mA		3	10		
	TPS76033	4.3 V < V <sub>I</sub> < 16, I <sub>O</sub> = 1 mA		3	10		
	TPS76038	4.8 V < V <sub>I</sub> < 16, I <sub>O</sub> = 1 mA		3	10		
	TPS76050	6 V < V <sub>I</sub> < 16, I <sub>O</sub> = 1 mA		3	10		
V <sub>n</sub>	Output noise voltage	BW = 300 Hz to 50 kHz, C <sub>O</sub> = 10 μF, T <sub>J</sub> = 25°C		190		μVrms	
Ripple rejection		f = 1 kHz, C <sub>O</sub> = 10 μF, T <sub>J</sub> = 25°C		63		dB	
Dropout voltage		I <sub>O</sub> = 0 mA, T <sub>J</sub> = 25°C		1	3	mV	
		I <sub>O</sub> = 0 mA			5		
		I <sub>O</sub> = 1 mA, T <sub>J</sub> = 25°C		7	10		
		I <sub>O</sub> = 1 mA			15		
		I <sub>O</sub> = 10 mA, T <sub>J</sub> = 25°C		40	60		
		I <sub>O</sub> = 10 mA			90		
		I <sub>O</sub> = 50 mA, T <sub>J</sub> = 25°C		120	150		
		I <sub>O</sub> = 50 mA			180		
Peak output current/current limit		T <sub>J</sub> = 25°C	100	125		mA	



# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050

## LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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**electrical characteristics over recommended operating free-air temperature range,  
 $V_I = V_{O(nom)} + 1\text{ V}$ ,  $I_O = 1\text{ mA}$ ,  $EN = V_I$ ,  $C_O = 1\text{ }\mu\text{F}$  (unless otherwise noted) (continued)**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
High level enable input			2			V
Low level enable input					0.8	V
$I_I$	Input current (EN)	$EN = 0\text{ V}$	-1	0	1	$\mu\text{A}$
		$EN = V_I$		2.5	5	$\mu\text{A}$

## TYPICAL CHARACTERISTICS

Table of Graphs

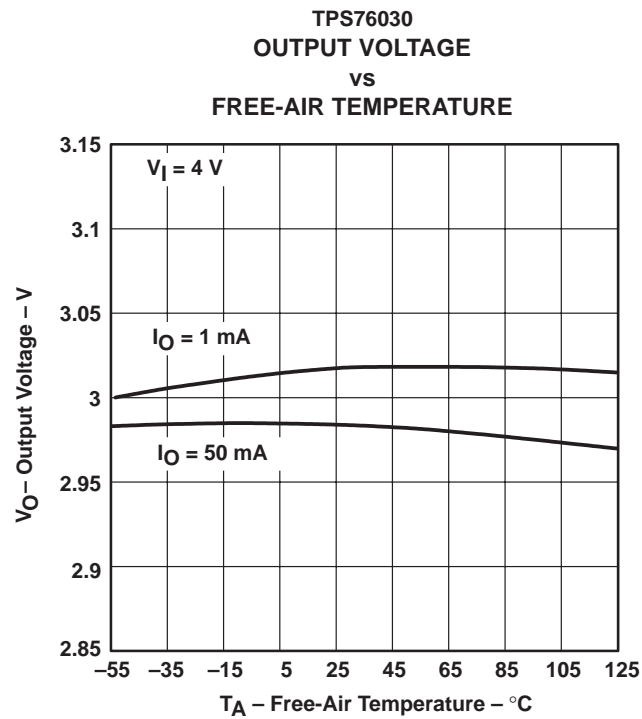
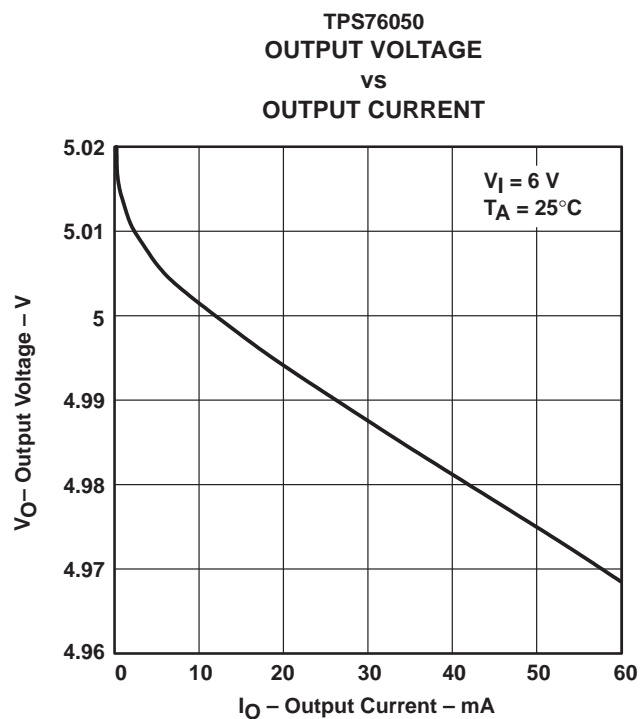
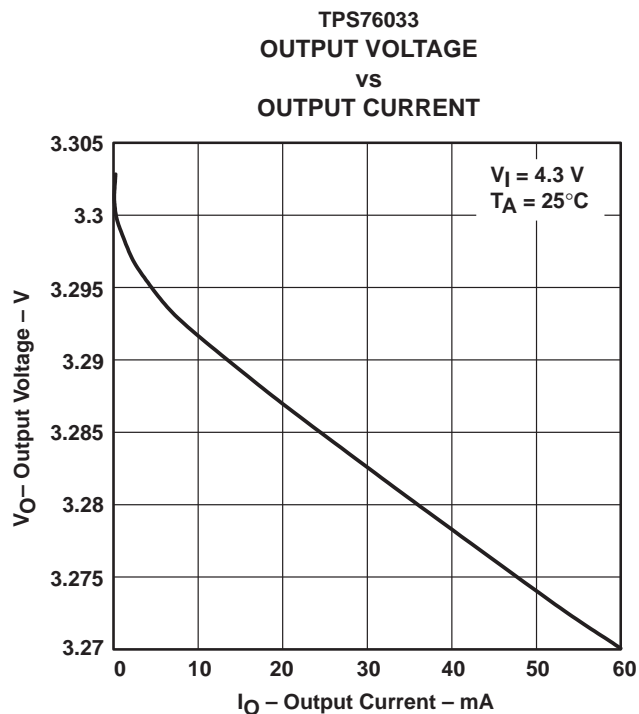
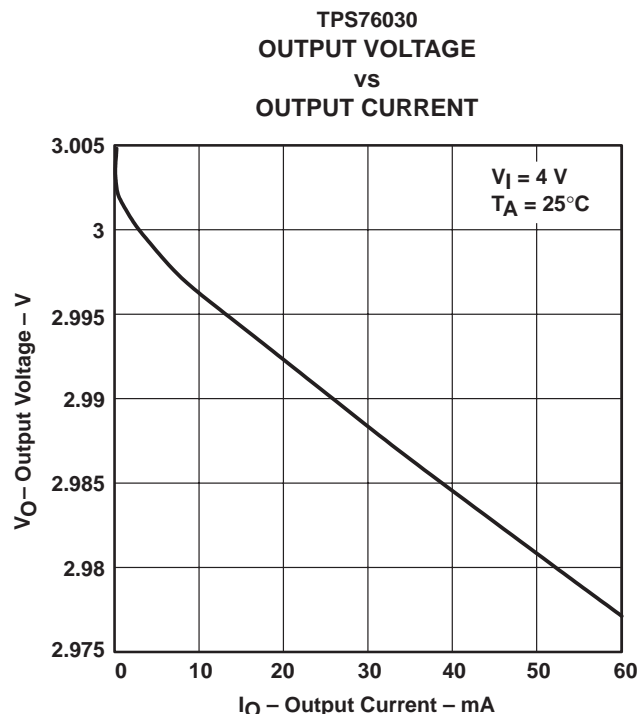
			FIGURE
$V_O$	Output voltage	vs Output current	1, 2, 3
		vs Free-air temperature	4, 5, 6
	Ground current	vs Free-air temperature	7, 8, 9
	Output noise	vs Frequency	10
$Z_O$	Output impedance	vs Frequency	11
$V_{DO}$	Dropout voltage	vs Free-air temperature	12
	Line transient response		13, 15
	Load transient response		14, 16



# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050 LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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## TYPICAL CHARACTERISTICS



# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050

## LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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### TYPICAL CHARACTERISTICS

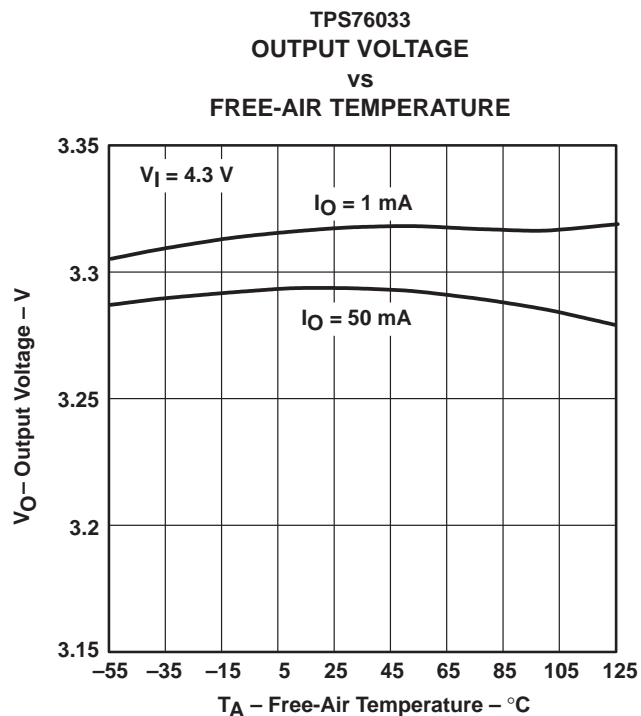


Figure 5

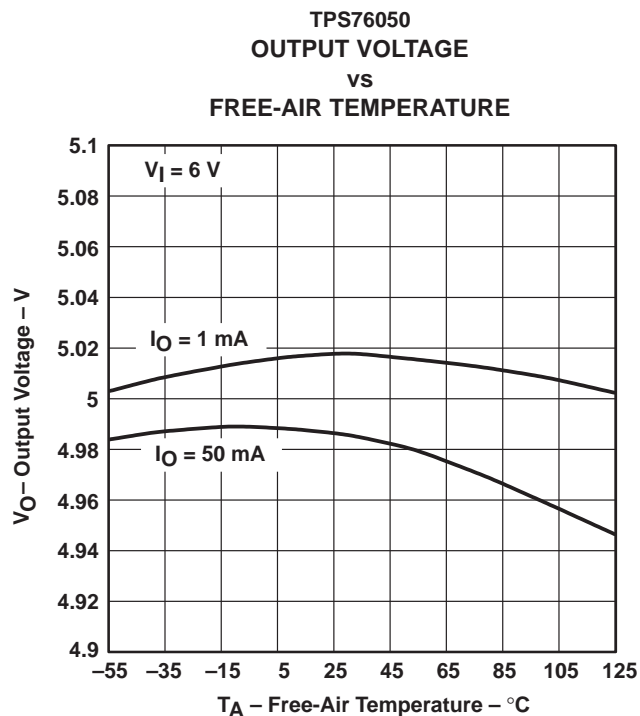


Figure 6

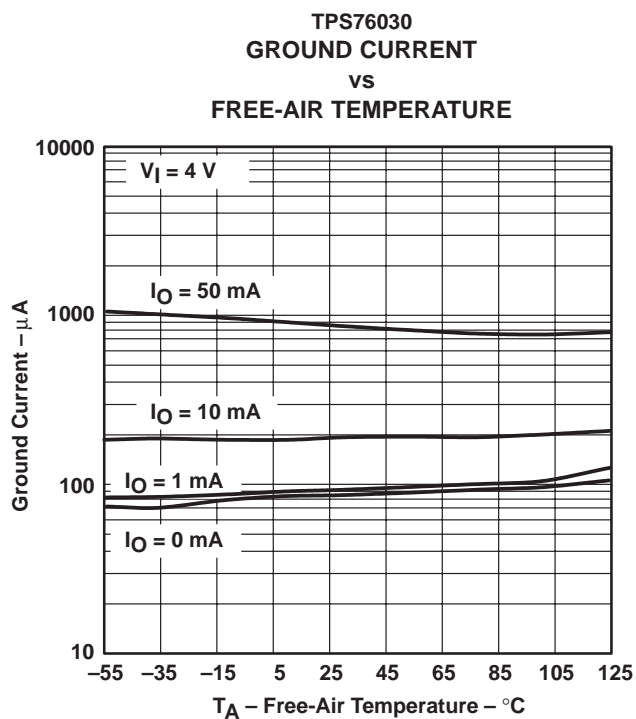


Figure 7

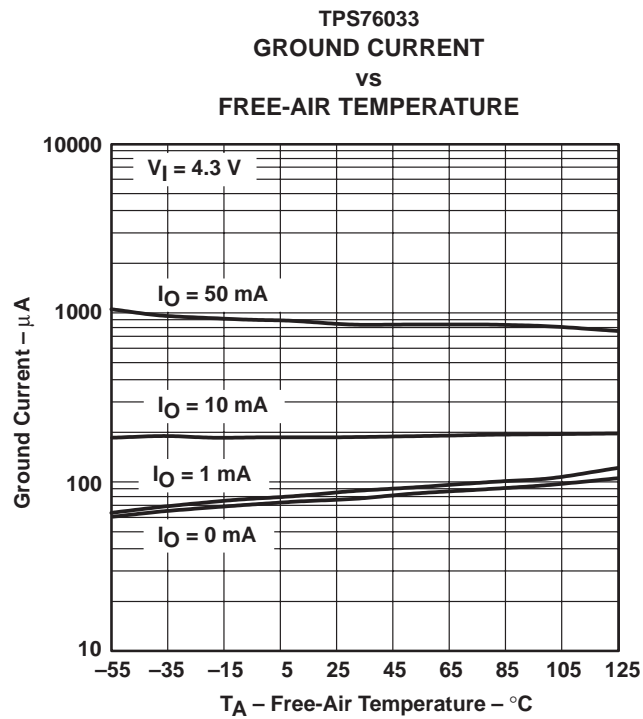


Figure 8

# TYPICAL CHARACTERISTICS

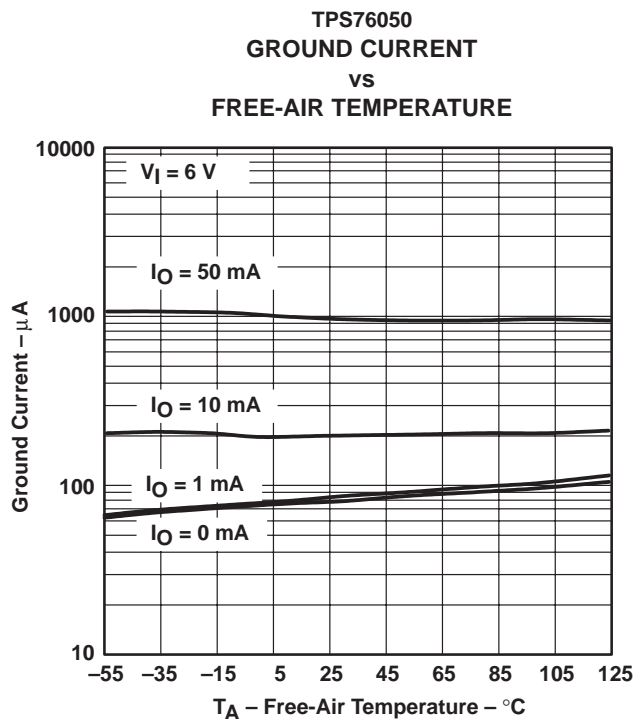


Figure 9

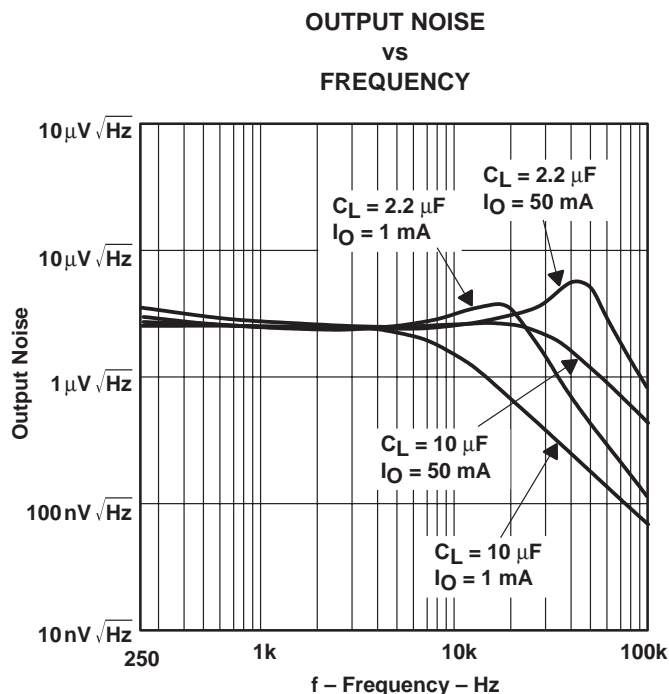


Figure 10

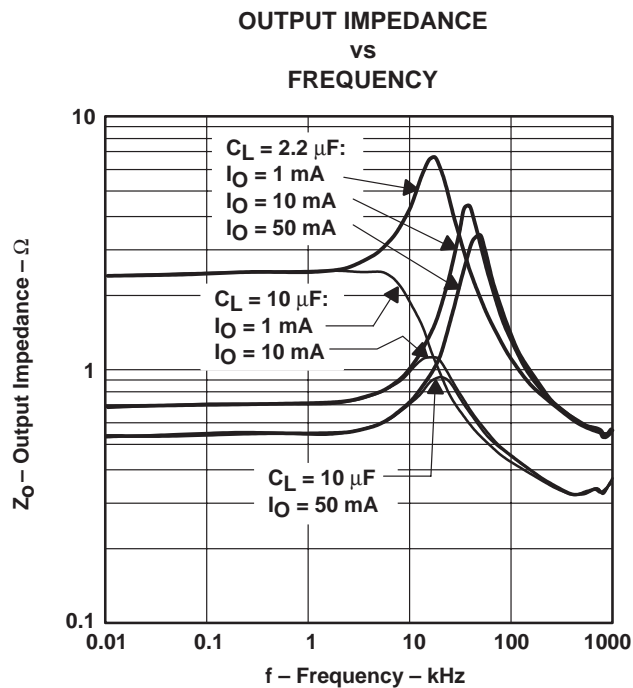


Figure 11

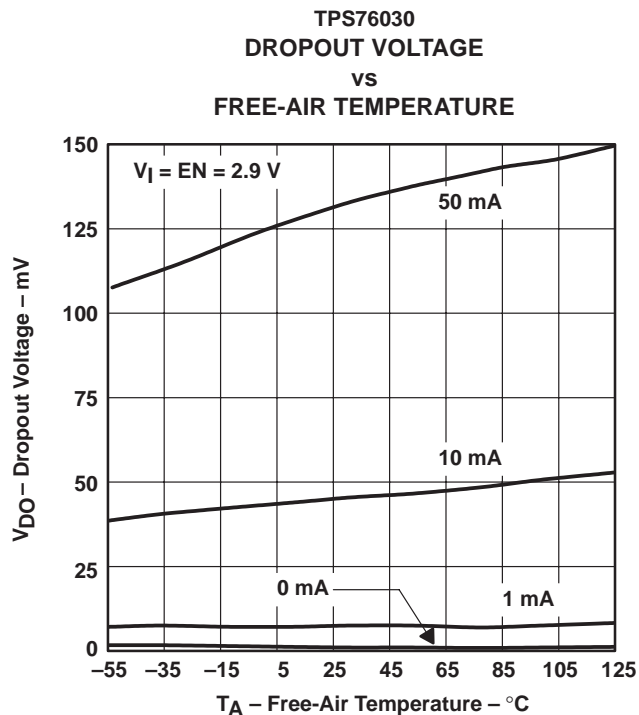


Figure 12

# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050

## LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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### TYPICAL CHARACTERISTICS

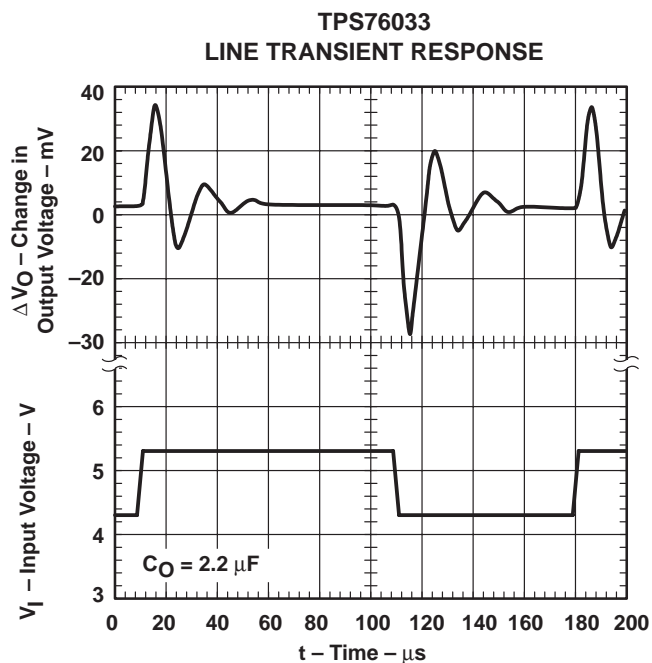


Figure 13

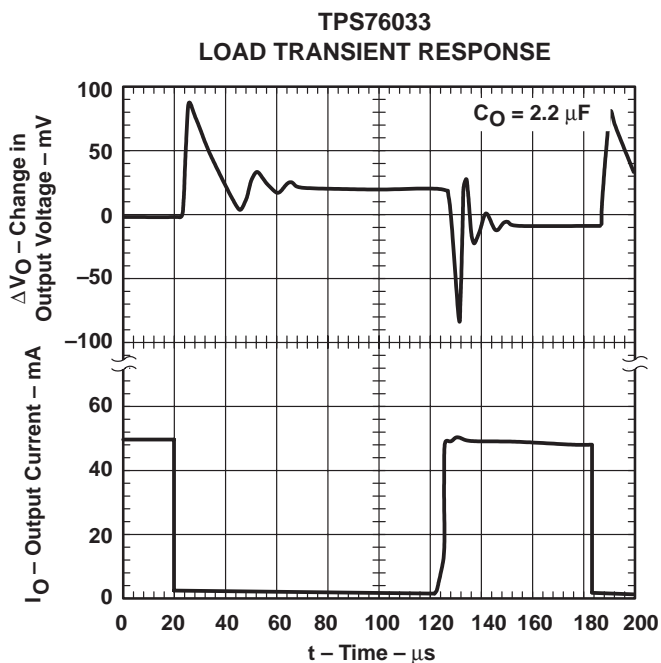


Figure 14

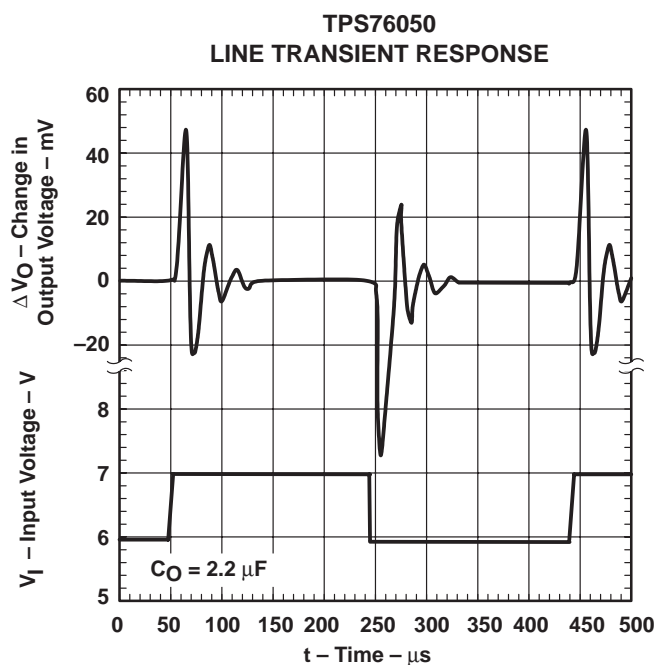


Figure 15

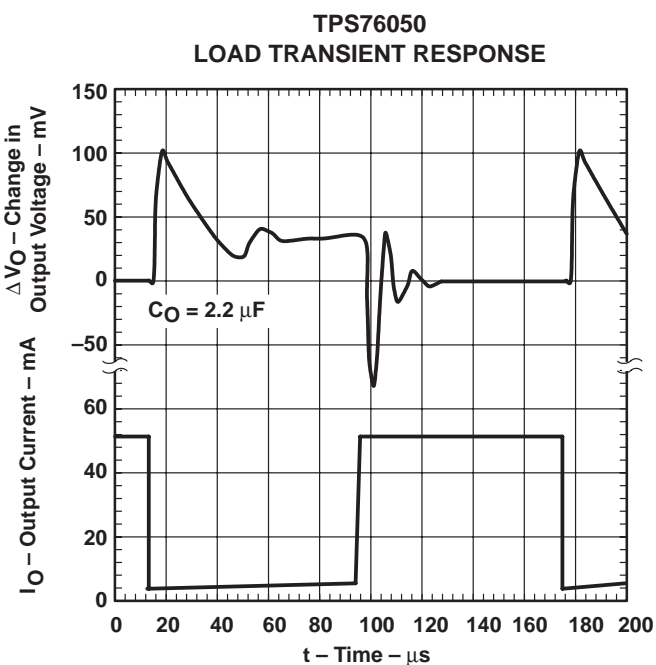


Figure 16



## APPLICATION INFORMATION

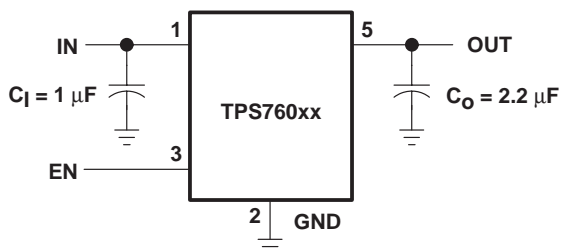


Figure 17. TPS760xx Typical Application

### over current protection

The over current protection circuit forces the TPS760xx into a constant current output mode when the load is excessive or the output is shorted to ground. Normal operation resumes when the fault condition is removed. An overload or short circuit may also activate the over temperature protection if the fault condition persists.

### over temperature protection

The thermal protection system shuts the TPS760xx down when the junction temperature exceeds 160°C. The device recovers and operates normally when the temperature drops below 150°C.

### input capacitor

A 0.047  $\mu$ F or larger ceramic decoupling capacitor with short leads connected between IN and GND is recommended. The decoupling capacitor may be omitted if there is a 1  $\mu$ F or larger electrolytic capacitor connected between IN and GND and located reasonably close to the TPS760xx. However, the small ceramic device is desirable even when the larger capacitor is present, if there is a lot of high frequency noise present in the system.

### output capacitor

Like all low dropout regulators, the TPS760xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 2.2  $\mu$ F and the ESR (equivalent series resistance) must be between 0.1  $\Omega$  and 20  $\Omega$ . Capacitor values of 2.5- $\mu$ F or larger are acceptable, provided the ESR is less than 20  $\Omega$ . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 2.2- $\mu$ F surface-mount solid-tantalum capacitors, including devices from Sprague, Kemet, and Nichicon, meet the ESR requirements stated above. Multilayer ceramic capacitors should have minimum values of 2.5  $\mu$ F over the full operating temperature range of the equipment.

### enable (EN)

A logic zero on the enable input shuts the TPS760xx off and reduces the supply current to less than 1  $\mu$ A. Pulling the enable input high causes normal operation to resume. If the enable feature is not used, EN should be connected to IN to keep the regulator on all of the time. The EN input must not be left floating.

# TPS76030, TPS76032, TPS76033, TPS76038, TPS76050 LOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

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## APPLICATION INFORMATION

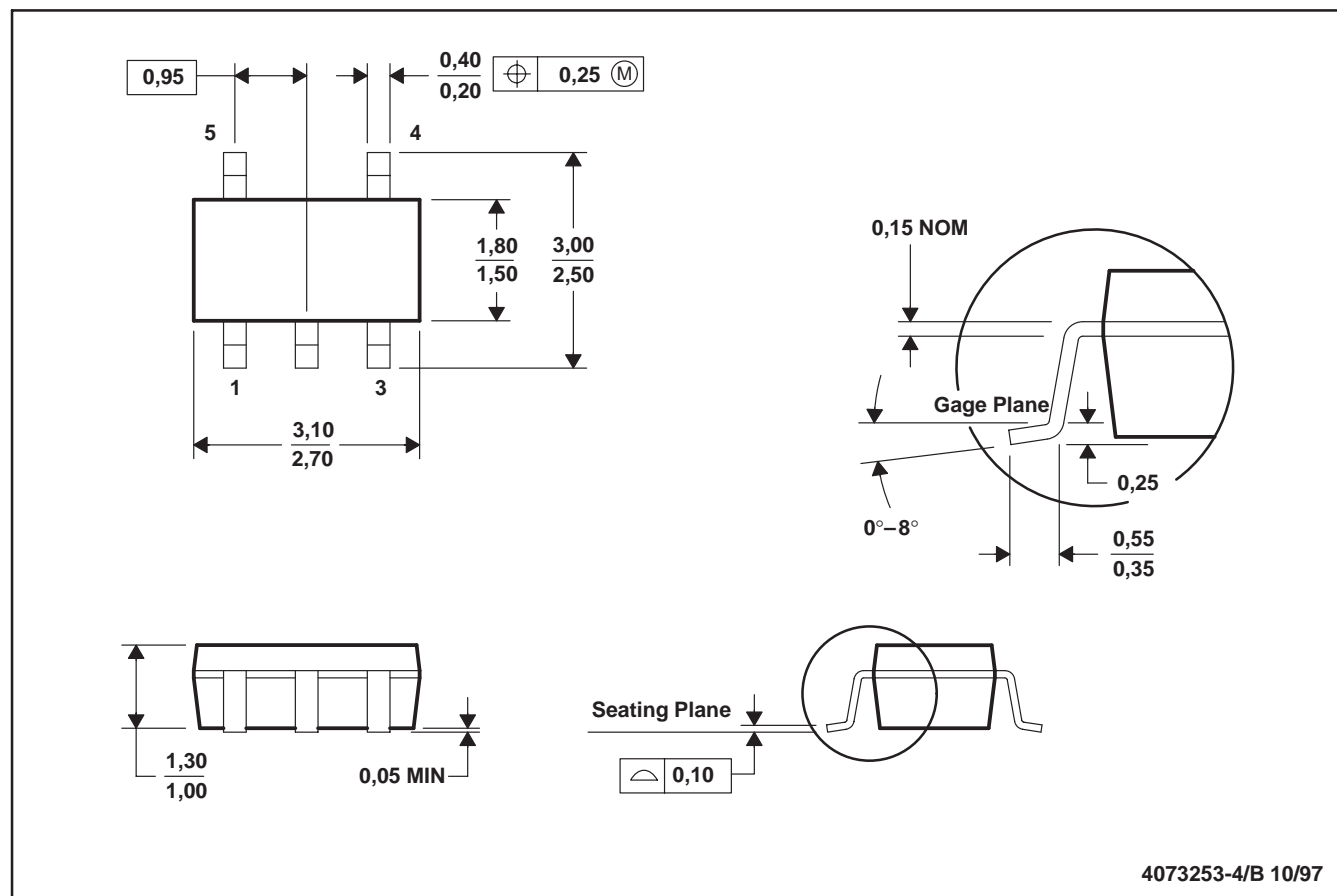
### reverse current path

The power transistor used in the TPS760xx has an inherent diode connected between IN and OUT as shown in the functional block diagram. This diode conducts current from the OUT terminal to the IN terminal whenever IN is lower than OUT by a diode drop. This condition does not damage the TPS760xx, provided the current is limited to 100mA.

## MECHANICAL DATA

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.  
B. This drawing is subject to change without notice.  
C. Body dimensions include mold flash or protrusion.

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